

BDX64 – A – B – C

PNP SILICON DARLINGTON POWER TRANSISTOR

The BDX64, BDX64A, BDX64B and BDX64C are mounted in TO-3 metal package.
High current power darlington designed for power amplification and switching applications.
The complementary NPN are BDX65, BDX65A, BDX65B, BDX65C.
Compliance to RoHS.

ABSOLUTE MAXIMUM RATINGS

Symbol	Ratings			Value	Unit
V_{CEO}	Collector-Emitter Voltage		BDX64	-60	V
			BDX64A	-80	
			BDX64B	-100	
			BDX64C	-120	
V_{CEV}	Collector-EmitterVoltage	$V_{BE}=-1.5\text{ V}$	BDX64	-60	V
			BDX64A	-80	
			BDX64B	-100	
			BDX64C	-120	
V_{EBO}	Emitter-Base Voltage			-5.0	V
I_C	Collector Current	$I_{C(RMS)}$	-12	A	
		I_{CM}	-16		
I_B	Base Current			0.2	A
P_T	Power Dissipation	@ $T_C = 25^\circ$		117	W
T_J	Junction Temperature			-55 to +200	$^\circ\text{C}$
T_S	Storage Temperature				

THERMAL CHARACTERISTICS

Symbol	Ratings		Value	Unit
R_{thJ-C}	Thermal Resistance, Junction to Case		1.5	$^\circ\text{C/W}$

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ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)		Min	Typ	Max	Unit
$V_{CE(SUS)}$	Collector-Emitter Breakdown Voltage (*)	$I_C = -0.1\text{ A}$ $I_B = 0$ $L = 25\text{mH}$	BDX64	-60	-	-	V
			BDX64A	-80	-	-	
			BDX64B	-100	-	-	
			BDX64C	-120	-	-	
I_{CEO}	Collector Cutoff Current	$V_{CE} = -30\text{ V}$	BDX64	-	-	-1.0	mA
		$V_{CE} = -40\text{ V}$	BDX64A	-	-		
		$V_{CE} = -50\text{ V}$	BDX64B	-	-		
		$V_{CE} = -60\text{ V}$	BDX64C	-	-		
I_{EBO}	Emitter Cutoff Current	$V_{BE} = -5\text{ V}$	BDX64	-	-	-5.0	mA
			BDX64A				
			BDX64B				
			BDX64C				
I_{CBO}	Collector-Base Cutoff Current	$V_{CBO} = -60\text{ V}$	BDX64	-	-	0.2	-
		$V_{CBO} = -40\text{ V}$ $T_{CASE} = 200^\circ\text{C}$		-	-	2	
		$V_{CBO} = -80\text{ V}$	BDX64A	-	-	0.2	
		$V_{CBO} = -50\text{ V}$ $T_{CASE} = 200^\circ\text{C}$		-	-	2	
		$V_{CBO} = -100\text{ V}$	BDX64B	-	-	0.2	
		$V_{CBO} = -60\text{ V}$ $T_{CASE} = 200^\circ\text{C}$		-	-	2	
		$V_{CBO} = -120\text{ V}$	BDX64C	-	-	0.2	
		$V_{CBO} = -70\text{ V}$ $T_{CASE} = 200^\circ$		-	-	2	
$V_{CE(SAT)}$	Collector-Emitter saturation Voltage (*)	$I_C = -5.0\text{ A}$ $I_B = -20\text{ mA}$	BDX64	-	-	-2	V
			BDX64A				
			BDX64B				
			BDX64C				
V_F	Forward Voltage (pulse method)	$I_F = 5\text{ A}$	BDX64	-	1.8	-	V
			BDX64A				
			BDX64B				
			BDX64C				
V_{BE}	Base-Emitter Voltage (*)	$I_C = -5.0\text{ A}$ $V_{CE} = -3\text{ V}$	BDX64	-	-	-2.5	V
			BDX64A				
			BDX64B				
			BDX64C				

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ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

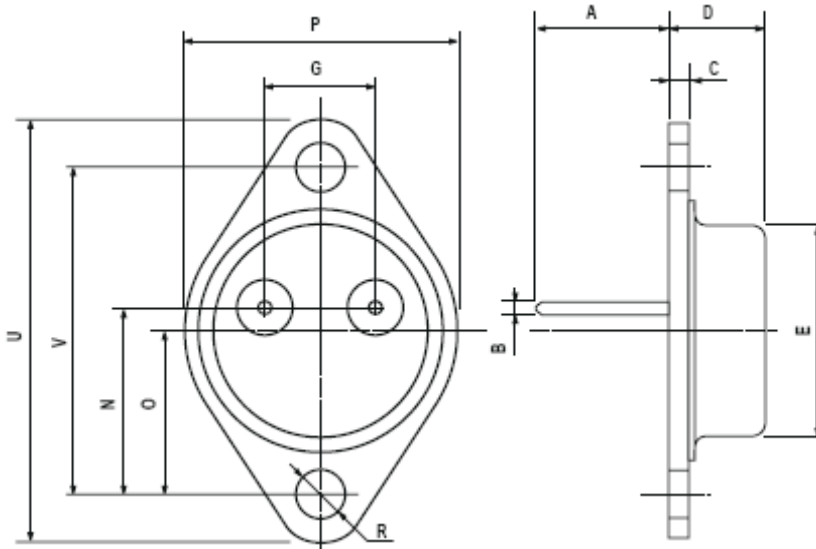
Symbol	Ratings	Test Condition(s)		Min	Typ	Max	Unit
F_{hfe}	Cut-off frequency	-V _{CE} =3 V -I _C =5 A	BDX64	-	80	-	kHz
			BDX64A				
			BDX64B				
			BDX64C				
f_T	Transition Frequency	V _{CE} =-3 V I _C =-5 A f=1 MHz	BDX64	-	7	-	MHz
			BDX64A				
			BDX64B				
			BDX64C				
h_{FE}	D.C. current gain (*)	-V _{CE} =-3 V -I _C =-1 A	BDX64	-	1500	-	-
			BDX64A				
			BDX64B				
			BDX64C				
		-V _{CE} =-3 V -I _C =-5 A	BDX64	1000	-	-	
			BDX64A				
			BDX64B				
			BDX64C				
		-V _{CE} =-3 V -I _C =-12 A	BDX64	-	750	-	
			BDX64A				
			BDX64B				
			BDX64C				

(*) Pulse Width ≈ 300 μs, Duty Cycle < 2.0%

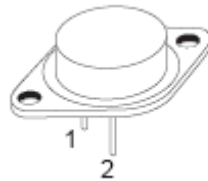
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MECHANICAL DATA CASE TO-3

DIMENSIONS (mm)		
	min	max
A	11	13.10
B	0.97	1.15
C	1.5	1.65
D	8.32	8.92
F	19	20
G	10.70	11.1
N	16.50	17.20
P	25	26
R	4	4.09
U	38.50	39.30
V	30	30.30



Pin 1 :	Base
Pin 2 :	Emitter
Case :	Collector



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